## **Applied Physics B Lasers and Optics**



# **Demonstration of broadband magnetic polymer composite absorber crossing** *S***‑ and** *C***‑bands**

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#### **Abstract**

In this paper, an ultra-thin microwave absorber with cross-resonator (CR) exhibiting a broad absorption bandwidth is designed and fabricated. Theoretical and experimental results show that the absorber has a wideband strong absorption in a frequency range from 2.2 to 6.8 GHz and from 2.2 to 5.4 GHz when incident electric feld is *y*-and *x*-polarized, respectively. The equivalent *L*–*C* circuit and energy loss density clarify the mechanism underlying observed absorption. Moreover, the oblique incidence performance of the proposed absorber is also analyzed and shows that the broad bandwidth can be maintained as incident angle increases up to 30 degrees for *y*-polarized wave and 60 degrees for *x*-polarized wave, respectively. And when incident angle is fxed at 30 degrees the absorption bandwidth can be achieved from 2.1 to 7.5 GHz with azimuth angle of 90 degrees for *x*-polarized wave.

## **1 Introduction**

Microwave absorber has continuously attracted enormous interest due to its widespread applications for prominent examples including electromagnetic (EM) interference, compatibility and stealth technology [[1–](#page-6-0)[6](#page-6-1)]. In 2008, Landy et al.[\[1\]](#page-6-0) frstly reported perfect metamaterial absorber, which soon inspired the development of microwave absorbers [[7,](#page-7-0)

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[8](#page-7-1)]. With the development of detective technology, improvement of low-frequency microwave absorption performance has been particularly important. Traditional microwave absorbers at low frequency are usually carried out based on a dielectric substrate [\[9](#page-7-2)[–11](#page-7-3)]. However, the alignment involved in such a design would make its fabrication process complicated and challenging. Large thickness is also needed for these absorbers to expand the limited bandwidth.

Recently, attempts have been made to improve lowfrequency absorbing properties with magnetic elements  $[12–20]$  $[12–20]$  $[12–20]$  $[12–20]$  $[12–20]$ . In Ref.  $[15]$  $[15]$ , a magnetic-type absorber (MA) based on cross resonator (CR) was realized for exhibiting a − 10 dB bandwidth from 1.67 to 3.7 GHz with a total thickness of 2.42 mm. A second-order cross fractal metamaterial structure for such purpose was proposed in Ref. [[17\]](#page-7-7). Chen et al. presented a multilayer MA to extend lowfrequency absorption bandwidth [\[12](#page-7-4)]. However, the working bandwidth depends on operation frequency and sufers from narrow bandwidth, which may impede their applications. In previous papers, Zhang et al.[\[14](#page-7-8)] have designed a needleshaped MA to improve the low-frequency properties, and the bandwidth could be extended with a relatively thinner thickness. In Refs. [\[7](#page-7-0)] and [\[15](#page-7-6)], the physics mechanisms of these cross-shaped absorbers can be explained by the destructive interference and equivalent circuit model. These two intriguing features, therefore, make it possible for us to design a simple MA in both S and C frequency regimes.

In this work, a facile approach is employed for achieving simultaneously ultra-thin and wideband microwave absorber using periodic CR pattern and magnetic polymer composite crossing *S*- and *C*-bands. Our proposed absorber exhibits wideband absorption properties demonstrated numerically as well as experimentally. Both the equivalent *L*–*C* resonant circuit and EM feld analysis are proposed to explain the physical mechanism. Finally, the oblique incidence performance of the proposed absorber varying is also given.

## **2 Design and experiment**

The schematic of the proposed MA is illustrated in Fig. [1a](#page-1-0) and b, which consists of arrays of CR pattern placed on top of a magnetic polymer composite with thickness *t*=2.0 mm. The period of the unit cell is  $a_r = 22$  mm,  $a_v = 12$  mm, and the dimensions of the CR patterns are  $l=8.0$  mm,  $w=1.0$  mm and  $t_n = 0.002$  mm. The magnetic polymer composite used throughout this work was prepared on the basis of epoxy resin flled with FeCo alloy powders at the weight ratio of 1:9 by blending, roll mixing, and vulcanizing [[21,](#page-7-9) [22](#page-7-10)]. The complex EM parameters (as shown in Fig. [2](#page-1-1)) were measured by Agilent 8720ET vector network analyzer based on refection/transmission technique by inserting the toroidal sample into a coaxial waveguide with the same inner and outer diameter as the sample. The EM parameters were derived from the scattering parameters (*S* parameters) based on the so-called Nicolson-Ross-Weir principle [\[23](#page-7-11)].

The fnite-diference time-domain (FDTD) solver CST Microwave Studio software (Version 2014) was used to demonstrate the microwave absorption properties of our design. A single unit cell was simulated with appropriate boundary conditions, as unit cell in both *x* and *y* directions, and open (add space) in *z* direction. And under this periodic boundary condition, the Floquet mods are TE and TM modes. Under TE mode, electric and magnetic felds are along *y*- and *x*-axis, respectively. And under TM mode, electric and magnetic felds are along *x*- and *y*-axis, respectively. EM plane waves were incident on the surface of the structure. In simulations, the material type of the CA pattern in simulations is lossy metal with electric conductivity of  $3.72 \times 10^7$  S/m. we can obtain all the relationships between the reflection coefficient and the geometric dimensions. For experiments, the MA was fabricated in the form of rubber board; the copper flm was pasted on the magnetic absorbing sheet with glue and the etched into arrays of CA pattern with the mechanical lithography method. The total area of the sample is  $200 \times 200$  mm<sup>2</sup>. An image of the fabricated MA is presented in Fig. [1c](#page-1-0). Agilent 8720ET vector network analyzer connected to two standard gain broadband antennas was employed to measure the proposed MA in an EM anechoic chamber.

Figure [3](#page-2-0) shows the simulated and measured refection coefficients. Owing to the asymmetric of the diagonal of the unit cell, the proposed MA shows dependent on the direction of the incident electric feld. When the incident electric feld is *y*-polarized as shown in Fig. [3](#page-2-0)(a), two absorption peaks can be observed clearly at the frequencies of 2.5 GHz and 4.8 GHz for simulation and 2.9 GHz and 4.5 GHz for measurements, respectively. It can also be seen that the simulated absorption bandwidth is achieved from 2.1 to 6.8 GHz and from 2.2 to 6.8 GHz for measurements. As depicted in Fig. [3](#page-2-0)(b), when the incident electric



<span id="page-1-1"></span>**Fig. 2** Measured relative electromagnetic parameters of the magnetic absorbing material as a function of frequency



<span id="page-1-0"></span>**Fig. 1 a** Front view of the unit cell, **b** cross-section schematic of the absorber, **c** the photography of the measured sample



<span id="page-2-0"></span>**Fig. 3** Simulated and measured refection coefficients for the proposed absorber with the incident eletric field propagating along **a** *y*-polarized and **b** *x*-polarized

feld is *x*-polarized, the resonant frequencies are 2.3 GHz, 3.9 GHz for simulation and 2.5 GHz, 4.1 GHz for measurement. The MA still exhibits broad absorption bandwidth from 2.2 to 5.8 GHz for simulation and from 2.2 to 5.4 GHz for measurement. However, there is a discrepancy between the simulated and measured results. Both the infnite sample size and actual EM parameters can afect the measured results. Meanwhile, the limited precision of fabrication geometry also afects the results. Despite of these discrepancies, the proposed MA is still able to sustain lowfrequency broadband absorption property. Some recently reported broadband microwave absorbers at low frequency are summarized for comparison in Table [1.](#page-2-1) It is apparent that the proposed MA operates in a higher frequency range with a wider bandwidth. In addition, the thickness of the proposed MA requires only 2 mm.

#### **3 Results and discussion**

Figure [4](#page-3-0) shows the simulated reflection coefficients of the proposed MA with diferent thickness. The absorption property is sensitive to the thickness. We can see that whenever the incident electric is *y*-or *x*-polarized, the two resonant frequencies gradually shift towards lower frequency as *t* increases. And then the high-frequency absorption peak gradually disappears and the absorption bandwidth becomes narrow. When the thickness is about 2 mm, the absorption bandwidth is widest. Due to the frequency-dispersive permeability of magnetic polymer composite, the design of ultrathin and broadband MA is more complicated compared with non-magnetic microwave absorber. As discussed in Refs.  $[15]$  $[15]$  and  $[16]$  $[16]$ , the authors have introduced the effect of frequency selective surfaces (FSSs) on the absorption characteristics of MA. As a result, we will analyze the introduction



a The incident electric feld is *y*-polarized

b The incident electric feld is *x*-polarized

 ${}^cE_{in}$  represents the incident electric field

absorbers at low-frequency microwave bands

<span id="page-2-1"></span>**Table 1** The recent reported broadband microwaves



<span id="page-3-0"></span>**Fig.** 4 Simulated refection coefficients with different thickness *t* when the incident electric field is **a** *y*-polarized and **b** *x*-polarized

of CR on the absorption performance by equivalent circuit and energy loss density.

To make a better understanding of the characteristics of the proposed MA, we study the dependence of dimensional parameter  $a_x$  on the absorption properties when other parameters are fxed as illustrated in Fig. [5](#page-3-1). First, when the incident electric feld is *y*-polarized (see Fig. [5](#page-3-1)a), it is observed that two resonant peaks can be generated with increases of  $a_x$ . When  $a_x = 22$  mm, the -10 dB absorption bandwidth is achieved from 2.1 to 6.8 GHz. Second, the similar phenomenon occurs when the incident electric feld is *x*-polarized as depicted in Fig. [5](#page-3-1)b. The − 10 dB absorption bandwidth is 2.2 to 5.8 GHz when  $a_x = 22$  mm. However, the low-frequency resonant peaks are gradually weaker with the increase of  $a<sub>x</sub>$  both in these two cases. The phenomenon can be explained by an equivalent *R*-*L*-*C* parallel circuit



<span id="page-3-1"></span>**Fig. 5** Simulated (**a**, **b**) and calculated (**c**, **d**) reflection coefficient with different geometrical parameter  $a_x$  for the proposed MA

[\[13–](#page-7-13)[15,](#page-7-6) [24](#page-7-14)[–27](#page-7-15)]. The total capacitances *C* can be described approximately by a formula  $C \approx l w \epsilon_0 (\epsilon_r + 1)/(2a_x)$ , and the total inductance *L* of the structure is approximately given by  $L \approx a_x l \ln (t/w) \mu_0 (\mu_r + 1)/2$ . Thus the equivalent input impedance  $z_{\text{in}}$  and reflection coefficient  $S_{11}$  of the proposed MA can be expressed by:

$$
z_d = iz_0 \sqrt{\frac{\mu_r}{\varepsilon_r}} \tan \left( 2\pi f t \frac{\sqrt{\mu_r \varepsilon_r}}{c} \right)
$$
 (1)

$$
z_{\rm in} = \frac{\left(j2\pi fL + \frac{1}{j2\pi fC}\right)z_d}{j2\pi fL + \frac{1}{j2\pi fC} + z_d}
$$
(2)

$$
S_{11}(dB) = 20 \cdot \log_{10} \left( \left| \frac{z_{in} - z_0}{z_{in} + z_0} \right| \right)
$$
 (3)

where *f* is the frequency the operating frequency,  $\mu_r$  and  $\varepsilon_r$ are the relative EM parameters of the magnetic absorbing substrate,  $z_d$  is the impedance of the absorber without CR pattern.

According to the transmission line theory and the above equations, we calculate the reflection coefficients with a different  $a_x$  as illustrated in Fig. [5c](#page-3-1) and d. These results show a good agreement compared with the simulated results. To reveal the reason of the absorption characteristic with a different  $a<sub>x</sub>$ , equivalent capacitance and inductance are calculated as depicted in Fig. [6.](#page-4-0) Figure [6](#page-4-0)a demonstrates that when  $a<sub>x</sub>$  varies from 10 to 22 mm, the capacitance is decreased by 53% while the inductance is increased by 178%. And when the incident electric feld is *x*-polarized, the capacitance is decreased by 63% while the inductance is increased by 357% as shown in Fig. [6](#page-4-0)b. It is obtained that the variation of  $a<sub>x</sub>$ directly affects the equivalent capacitance and inductance,

which, therefore, determines the position of low-frequency and high-frequency absorption peak, respectively [[16](#page-7-12)].

To further investigate the underlying absorption mechanism and to understand its various contributions, we computationally monitor energy dissipation in the proposed MA. The simulated energy loss density at resonance frequency is shown in Figs. [7](#page-5-0) and [8](#page-5-1) for the structure as a whole. We can clearly see that the electric feld is mainly focused at the ends of CR along the incident electric feld direction, and the strong magnetic feld is mainly distributed at the left and right edges of CR but focused at the center of CR. Otherwise, according to the scale of the energy loss density, the loss at low frequency is larger than that at high frequency which demonstrates the same result for both electric loss density and magnetic loss density. Simulations reveal that the majority of energy is dissipated as magnetic loss which is an order of magnitude greater than the dielectric loss. As a result, both the electric loss and magnetic loss contribute to the broad absorption bandwidth.

Finally, the results in the above sections are all for normal incidence. But in practice, the EM wave may incident from diferent directions. So we frst study the oblique incidence performance of the proposed absorber. Figure [9](#page-6-2) illustrates the simulated reflection coefficients under different incident angles when the incident electric feld is *y*-and *x*-polarized, respectively. From Fig. [9](#page-6-2)a, it is shown that the value of the reflection coefficient gradually increases as incident angle increases. The operation bandwidth is also reduced. When the incident angle is  $30^{\circ}$ , the  $-10$  dB bandwidth can be achieved from 2.3 to 5.8 GHz. However, this phenomenon is diferent when the incident electric feld is *x*-polarized as shown in Fig. [9b](#page-6-2). The maximum reflection coefficient smoothly decreases and the operation bandwidth is increased when the incident angle increases to 45°, whereas the refection coefficient increases when incident angle is larger than



<span id="page-4-0"></span>**Fig. 6** The calculated results of capacitance *C* and inductance *L* for diferent geometrical parameter ax when the incident electric feld is **a** *y*-polarized and **b** *x*-polarized

<span id="page-5-0"></span>**Fig. 7** The normalized Energy loss density when incident electric feld is *y*-polarized: electric loss density at **a** 2.5 GHz and **c** 4.8 GHz, magnetic loss density at **b** 2.5 GHz and **d** 4.8 GHz



<span id="page-5-1"></span>**Fig. 8** The normalized energy loss density when incident electric feld is *x*-polarized: electric loss density at **a** 2.3 GHz and **c** 3.9 GHz, magnetic loss density at **b** 2.3 GHz and **c** 3.9 GHz

60°. In this case, the − 10 dB bandwidth can be achieved from 2.3 to 8.0 GHz.

Secondly, we investigate the low-frequency absorption properties of the proposed MA with diferent azimuth angle  $\varphi$  when incident angle  $\theta$  is fixed under 30 degrees (angle *θ* and *φ* are defned as those formed between the propagation vector of incident waves and the *z*-axis over *xz*- and *yz*-plane, respectively) as shown in Fig. [10.](#page-6-3) It can be easily observed that the low-frequency resonant peak almost remains the same with the increase of azimuth angle for both the two cases in Fig. [10.](#page-6-3) When the incident electric field is *y*-polarized (see in Fig. [10a](#page-6-3)) the high-frequency resonant peak tends to shift toward lower frequency, and the absorption bandwidth decreases with the increase of  $\varphi$ . However, the variation is different in Fig. [10b](#page-6-3). The high-frequency resonant peak shifts toward higher frequency, and the absorption bandwidth increases with the increase of  $\varphi$ . When  $\varphi$  = 90 degrees, the absorption bandwidth can be achieved from 2.1 to 7.5 GHz.



<span id="page-6-2"></span>**Fig.** 9 Simulated reflection coefficients under different incident angle from 0° to 75° when incident electric field is **a** *y*-polarized and **b** *x*-polarized



<span id="page-6-3"></span>**Fig. 10** Simulated refection spectrums by varying the azimuth angle when the incident electric feld is **a** *y*-polarized and **b** *x*- polarized

### **4 Conclusions**

In this work, we have presented an ultra-thin, low-frequency and wideband magnetic-type microwave absorber. The measured results show that the proposed absorber has a low-frequency wideband strong absorption in a frequency range from 2.2 to 6.8 GHz and from 2.2 to 5.4 GHz when incident electric feld is *y*-and *x*-polarized, respectively. The low-frequency absorption characteristics can be controlled based on the equivalent *L*–*C* circuit theory. The absorptive mechanism of the proposed absorber is contributed to the electric loss and magnetic loss by energy loss density. Finally, we have revealed the oblique incidence properties of the proposed absorber. The broad bandwidth can be maintained as incident angle increases up to 30 degrees for *y*-polarized and 60 degrees for *x*-polarized, respectively. Meanwhile, when the incident angle is fxed at 30 degrees and the incident feld is *x*-polarized, the absorption bandwidth can be achieved from 2.1 to 7.5 GHz with azimuth angle of 90 degrees.

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